TO-257

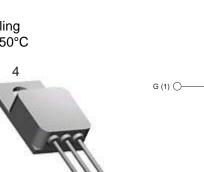
## **Normally-ON Trench Silicon Carbide Power JFET FEATURES:**

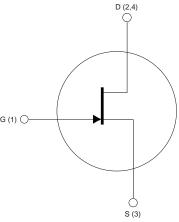
# SemiSouth Die Inside

- · Hermetic TO-257 Packaging
- 200°C Maximum Operating Temperature (260°C Contact Factory)
- Available Screening:
  - MIL-PRF-19500 Equivalent
  - Space Level
  - MIL-STD-750 Methods & Conditions
- Inherent Radiation Tolerance >100K TID
- Positive Temperature Coefficient for Ease of Paralleling
- Extremely Fast Switching with No "Tail" Current at 150°C
- 1200 Volt Drain-Source Blocking Voltage
- $\mbox{RDS}_{\mbox{\tiny (on)max}}$  of 0.045  $\Omega$  Voltage Controlled
- Low Gate Charge
- · Low Intrinsic Capacitance

## **APPLICATIONS:**

- Satellite Solar Inverters
- Mil Spec Power Supplies
  - Switch Mode
  - Uninterrupted
- Jet Engine Electronics
- Down-hole Electronics (Motor / Compressor Control)





**Product Summary** 

1200

0.045

TBD

V

Ω

μJ

 $BV_{DS}$ 

RDS<sub>(ON)max</sub>

 $E_{TS,typ}$ 

Internal Schematic

Non-isolated tab version shown. For isolated tab version, tab (4) is No Connect.

### **MAXIMUM RATINGS**

Parameter	Symbol	Conditions	Value	Unit	
Continuous Drain Current	I <sub>D, Tj=125</sub>	T <sub>j</sub> = 125 °C	50	А	
Continuous Diain Current	I <sub>D, Tj=150</sub>	T <sub>j</sub> = 150 °C	40		
Pulsed Drain Current (1)	I <sub>DM</sub>	T <sub>c</sub> = 25 °C	150	А	
Short Circuit Withstand Time	t <sub>sc</sub>	$V_{DD}$ < 800 V, $T_{C}$ < 125 °C	50	μS	
Power Dissipation	$P_{D}$	T <sub>c</sub> = 25 °C	TBD	W	
Gate-Source Voltage	$V_{GS}$	AC <sup>(2)</sup>	-15 to +15	V	
Operating and Storage Temperature	$T_j$ , $T_{j,stg}$		-55 to +200*	°C	
Lead Temperature for Soldering	$T_{sold}$	1/8" from case < 10 s	260	°C	

<sup>(1)</sup> Limited by pulse width

#### THERMAL CHARACTERISTICS

		Value		
Parameter	Symbol	Тур	Max	Unit
Thermal Resistance, junction-to-case	$R_{th,JC}$	-	TBD	°C / W
Thermal Resistance, junction-to-ambient	$R_{th,JA}$	-	TBD	C/VV

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<sup>(2)</sup>  $Rg_{EXT} = 1$  ohm,  $t_p < 200$ ns, see Figure 5 for static conditions

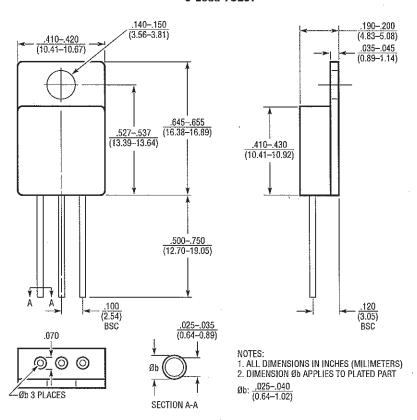
<sup>\*</sup>Consult factory for 260°C

## **ELECTRICAL CHARACTERISTICS**

			Value			
Symbol	Conditions	Min	Тур	Max	Unit	
BV <sub>DS</sub>	$V_{GS}$ = -15 V, $I_D$ = 600 $\mu A$	1200	-	-	V	
	$V_{DS} = 1200 \text{ V}, V_{GS} = -15 \text{ V},$		2	20		
	Tj = 25°C	-				
DSS	$V_{DS} = 1200 \text{ V}, V_{GS} = -15 \text{ V},$		20	μA 400	μΑ	
	Tj = 150°C	-	20			
	$V_{GS} = -15 \text{ V}, V_{DS} = 0 \text{V}$	-	-0.1	-0.6	mA	
¹GSS	$V_{GS} = -15 \text{ V}, V_{DS} = 1200 \text{V}$	0.1 -		IIIA		
	I <sub>D</sub> = 40 A, V <sub>GS</sub> = 2 V,		0.035		T	
Rose )	Tj = 25 °C	-	0.035	0.045	Ω	
, , D2(ou)	$I_D = 40 \text{ A}, V_{GS} = 2 \text{ V},$	_	0.07	_		
			0.07			
V <sub>GS(th)</sub>		-6.00	-	-4.00	V	
I <sub>GFWD</sub>	$V_{GS} = 2 V$	-	0	-	mA	
R <sub>G</sub>	f = 1 MHz, drain-source shorted	-	4	-	Ω	
R <sub>G(on)</sub>	V <sub>GS</sub> >2.7V	-	0.25	-	Ω	
C <sub>iss</sub>		-	1340	-	pF	
C <sub>oss</sub>	$V_{DD} = 100 V$	-	206	-		
C <sub>rss</sub>		-	194	-		
	$V_{DS} = 0 \text{ V to } 600 \text{ V},$		110			
C <sub>o(er)</sub>	$V_{GS} = 0 V$	-   110	-			
t <sub>on</sub>		-	TBD	-	- ns	
t <sub>r</sub>		-	TBD	-		
t <sub>off</sub>	V = 600 V I = 40 A	-	TBD	-		
t <sub>f</sub>		-	TBD	-		
E <sub>on</sub>	inductive Load, I <sub>J</sub> = 25 C	-	TBD	-		
E <sub>off</sub>		-	TBD	-	μЈ	
E <sub>ts</sub>		-	TBD	-		
t <sub>on</sub>		-	TBD	-		
t <sub>r</sub>		-	TBD	-	ns	
	$V_{DS} = 600 \text{ V}, I_{D} = 40 \text{ A},$	-	TBD	-		
t <sub>f</sub>	Inductive Load, T <sub>J</sub> = 150°C	-	TBD	-		
	· · ·	-	TBD	-		
		-	TBD	-	μJ	
		-	TBD	-	i '	
		-	65	-		
		-		-	nC	
	$V_{GS} = + 2.5 V$	_	-	1	"	
	BV <sub>DS</sub>	BV <sub>DS</sub>   V <sub>GS</sub> = -15 V, I <sub>D</sub> = 600 μA     V <sub>DS</sub> = 1200 V, V <sub>GS</sub> = -15 V,     Tj = 25°C     V <sub>DS</sub> = 1200 V, V <sub>GS</sub> = -15 V,     Tj = 150°C     V <sub>GS</sub> = -15 V, V <sub>DS</sub> = 0V     V <sub>GS</sub> = -15 V, V <sub>DS</sub> = 1200V     V <sub>GS</sub> = -15 V, V <sub>DS</sub> = 1200V     I <sub>D</sub> = 40 A, V <sub>GS</sub> = 2 V,     Tj = 25°C     I <sub>D</sub> = 40 A, V <sub>GS</sub> = 2 V,     Tj = 100°C     V <sub>GS</sub> (th)   V <sub>DS</sub> = 1 V, I <sub>D</sub> = 34mA     I <sub>GFWD</sub>   V <sub>GS</sub> = 2 V     R <sub>G</sub>   f = 1 MHz, drain-source shorted     R <sub>G</sub> (on)   V <sub>GS</sub> > 2.7V     C <sub>ISS</sub>     C <sub>OSS</sub>   V <sub>DD</sub> = 100 V     C <sub>rss</sub>   V <sub>DS</sub> = 0 V to 600 V,     V <sub>GS</sub> = 0 V     t <sub>on</sub>   t <sub>r</sub>   t <sub>off</sub>     t <sub>off</sub>   E <sub>ts</sub>   t <sub>on</sub>     t <sub>r</sub>   t <sub>off</sub>   E <sub>ts</sub>     t <sub>off</sub>   V <sub>DS</sub> = 600 V, I <sub>D</sub> = 40 A,     Inductive Load, T <sub>J</sub> = 25°C     E <sub>on</sub>   E <sub>off</sub>     E <sub>ts</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>     C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>   C <sub>O</sub>	BV <sub>DS</sub>	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	

#### **MECHANICAL DRAWING**

#### 3-Lead T0257



#### ORDERING INFORMATION

Base Part Number	Configuration	Package	Junction Temp. Range	Processing			
ASJD1200R045	Blank= Non-isolated Tab	Y=TO-257	- EL	Blank			
	S= Isolated Tab		EX	<b>/</b> V			
				/S			
Temp Ranges:	EL= Elevated Temp. Range, -55°C to 200°C (T <sub>J</sub> )						
	EX= Extreme Temp. Range, -55°C to 260°C (T <sub>1</sub> ) (consult factory)						

Processing: Blank = Commercial / Standard Processing

MIL-PRF-19500 Equivalent Processing Available Per SCD

/V= JANTX MIL-PRF-19500 Equivalent (future standard offering) /S= JANS MIL-PRF-19500 Equivalent (future standard offering)

Example Part Numbers: ASJD1200R045SY-EL

ASJD1200R045Y-EX

SemiSouth has commercial plastic versions of this product available. Please refer to the SemiSouth website http://www.semisouth.com/products/products.html for datasheet specifications and ordering information. The SemiSouth part number is SJDP120R045 and is supplied in a TO-247 plastic package.

**DOCUMENT TITLE** 

Normally-ON Trench Silicon Carbide Power JFET

Rev # History Release Date Status

0.0 Initial Release December 2010 Advanced Information